DECLARATION and POWER OF ATTORNEY

ATTORNEY'S DOCKET NO.: PHNL000139

As	a below	named	inventor,	I hereby	declare	that:

My residence, post office address and citizenship are as stated below next to my name.

I believe I am the original, first and sole inventor (if only one name is listed below) or an original, first joint inventor (if plural names are listed below) of the subject matter which is claimed and for which a patent is sought on the invention entitled

Semiconductor device with an integrated CMOS circuit with MOS transistors having silicon-germanium (Sl_{1-x}Ge_x) gate electrodes, and method of manufacturing same"

the specification of which (cl	neck one)	
is attached hereto.	•	
was filed on	as Application Serial No.	and was amended on
		(if applicable).
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I hereby state that I have reviewed and understand the contents of the above-identified specification, including the claims, as amended by the amendment(s) referred to above.

I acknowledge the duty to disclose information which is material to patentability of this application in accordance with Title 37, Code of Federal Regulations, §1.56(a).

I hereby claim foreign priority benefits under Title 35, United States Code, § 119 of any foreign application(s) for patent or inventor's certificate listed below and have also identified below any foreign application for patent or inventor's certificate having a filing date before that of the application on which priority is claimed:

PRIOR FOREIGN APPLICATION(S)

COUNTRY	APP. NUMBER	DATE OF FILING (DATE, MONTH, YEAR)	PRIORITY CLAIMED UNDER 35 U.S.C. 119
Europa	00200540.3	17 February 2000	YES
Europa	00201028.8	21 March 2000	YES

I hereby claim the benefit under Title 35, United States Code, §120 of any United States application(s) listed below and, insofar as the subject matter of each of the claims of this application is not disclosed in the prior United States application in the manner provided by the first paragraph of Title 35 United States Code, §112, I acknowledge the duty to disclose material information as defined in Title 37, Code of Federal Regulations, §1,56(a) which occurred between the filing date of the prior application and the national or PCT international filing date of this application:

PRIOR UNITED STATES APPLICATION(S)

APPLICATION SERIAL NUMBER	FILING DATE	STATUS (PATENTED, PENDING, ABANDONED)
\$ 100 3 000 200 200 200 200 200 200 200 200 200		

Diereby declare that all statements made herein of my own knowledge are true and that all statements made on information and belief are believed to be true; and further that these statements were made with the knowledge that willful false statements and the like so made are punishable by fine or imprisonment, or both, under Section 1001 of Title 18 of the United States Code and that such willful false statements may jeopardize the validity of the application or any patent issued thereon.

Pewer OF ATTORNEY: As a named inventor, I hereby appoint the following attorney(s) and/or agent(s) to prosecute this application and transact all business in the Patent and Trademark Office connected therewith. (list name and registration number)

Jack E. Haken, Reg. No. 26,902 Michael E. Marion, Reg. No. 34,266 Edward M. Blocker, Reg. No. 30,245

SEND CORRESPONDENCE TO: Corporate Patent Counsel;	DIRECT TELEPHONE CALLS TO:		
U.S. Philips Corporation; 580 White Plains Road;	(name and telephone No.)		
Tarrytown, NY 10591	(914) 332-0222		

Dated: 2 Febr	uary 2001	Inventor's Signature:		
Full Name of Inventor	Last Name PONOMAREV	First Name Youri	Middle Name	
Residence & Citizenship	City Eindhoven	State or Foreign Country The Netherlands	Country of Citizenship	
Post Office Address	Street Prof. Holstlaan 6	City 5656 AA Eindhoven	State or Country The Netherlands	Zip Code



ÎN THE UNITED STATES PATENT AND TRADEMARK OFFICE In re Application of Atty. Docket YOURI PONOMAREV NL 000139

Gerial No.

Filed: CONCURRENTLY

SEMICONDUCTOR DEVICE WITH AN INTEGRATED CMOS CIRCUIT WITH MOS TRANSISTORS HAVING SILICON-GERMANIUM (Sl_1-xGe_x) GATE ELECTRODES, AND METHOD OF MANUFACTURING SAME

Commissioner for Patents Washington, D.C. 20231

APPOINTMENT OF ASSOCIATES

Sir:

The undersigned Attorney of Record hereby revokes all prior appointments (if any) of Associate Attorney(s) or Agent(s) in the above-captioned case and appoints:

STEVEN R. BIREN

(Registration No. 26,531)

c/o U.S. PHILIPS CORPORATION, Intellectual Property Department, 580 White Plains Road, Tarrytown, New York 10591, his Associate Attorney(s)/Agent(s) with all the usual powers to prosecute the above-identified application and any division or continuation thereof, to make alterations and amendments therein, and to transact all business in the Patent and Trademark Office connected therewith.

ALL CORRESPONDENCE CONCERNING THIS APPLICATION AND THE LETTERS PATENT WHEN GRANTED SHOULD BE ADDRESSED TO THE UNDERSIGNED ATTORNEY OF RECORD.

Michael F. Marion, Reg. 32,266 Attorney of Record

Dated at Tarrytown, New York this 14th day of February 2001.